

HiPerFRED²

$$V_{RRM} = 300V$$

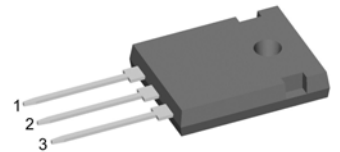
$$I_{FAV} = 2 \times 15A$$

$$t_{rr} = 35ns$$

High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DPG30C300HB



Backside: cathode

**Features / Advantages:**

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

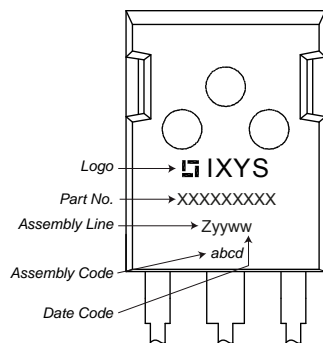
- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

| Fast Diode | | | | Ratings | | |
|------------|--|---|-------------------------|---------|------|------------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 300 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 300 | V |
| I_R | reverse current, drain current | $V_R = 300 V$ | $T_{VJ} = 25^{\circ}C$ | | 1 | μA |
| | | $V_R = 300 V$ | $T_{VJ} = 150^{\circ}C$ | | 0.08 | mA |
| V_F | forward voltage drop | $I_F = 15 A$ | $T_{VJ} = 25^{\circ}C$ | | 1.25 | V |
| | | $I_F = 30 A$ | | | 1.50 | V |
| | | $I_F = 15 A$ | $T_{VJ} = 150^{\circ}C$ | | 1.00 | V |
| | | $I_F = 30 A$ | | | 1.27 | V |
| I_{FAV} | average forward current | $T_C = 145^{\circ}C$ rectangular $d = 0.5$ | $T_{VJ} = 175^{\circ}C$ | | 15 | A |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 175^{\circ}C$ | | 0.69 | V |
| r_F | slope resistance | | | | 17.3 | m Ω |
| R_{thJC} | thermal resistance junction to case | | | | 1.7 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | 0.25 | | K/W |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 90 | W |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 240 | A |
| C_J | junction capacitance | $V_R = 150 V f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 20 | pF |
| I_{RM} | max. reverse recovery current | } $I_F = 15 A; V_R = 200 V$ $-di_F/dt = 200 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 3 | A |
| t_{rr} | reverse recovery time | | $T_{VJ} = 125^{\circ}C$ | | 6.5 | A |
| | | | $T_{VJ} = 25^{\circ}C$ | | 35 | ns |
| | | | $T_{VJ} = 125^{\circ}C$ | | 55 | ns |

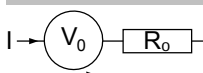
| Package TO-247 | | | Ratings | | | |
|----------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal ¹⁾ | | | 50 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 175 | °C |
| T_{op} | operation temperature | | -55 | | 150 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| M_D | mounting torque | | 0.8 | | 1.2 | Nm |
| F_C | mounting force with clip | | 20 | | 120 | N |

Product Marking

Part number

D = Diode
 P = HiPerFRED
 G = extreme fast
 30 = Current Rating [A]
 C = Common Cathode
 300 = Reverse Voltage [V]
 HB = TO-247AD (3)

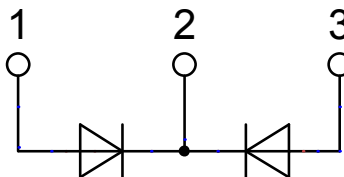
| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | DPG30C300HB | DPG30C300HB | Tube | 30 | 502567 |

| Similar Part | Package | Voltage class |
|--------------|----------------------|---------------|
| DPG30C300PB | TO-220AB (3) | 300 |
| DPG30C300PC | TO-263AB (D2Pak) (2) | 300 |

Equivalent Circuits for Simulation
** on die level*
 $T_{VJ} = 175\text{ °C}$

Fast Diode

| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0.69 | V |
| $R_{0\ max}$ | slope resistance * | 14.7 | mΩ |

Outlines TO-247



Fast Diode

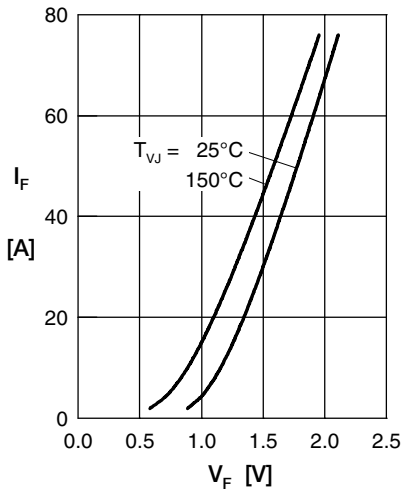


Fig. 1 Forward current I_F versus V_F

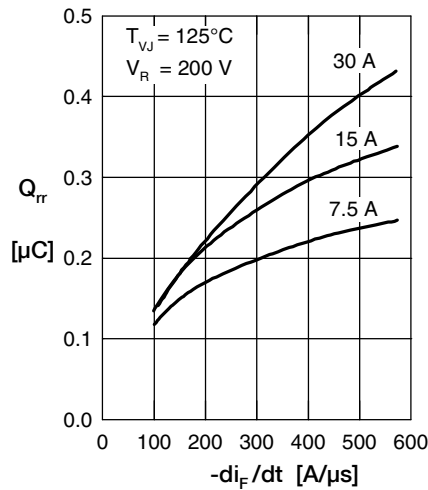


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

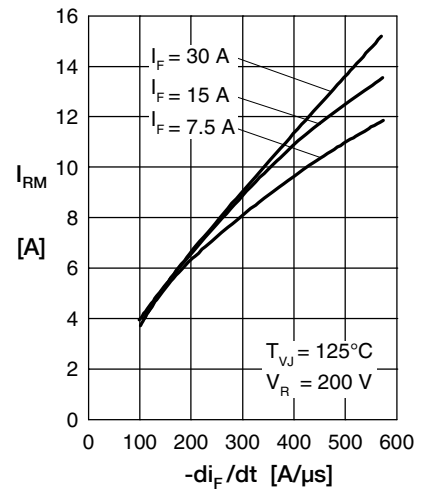


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

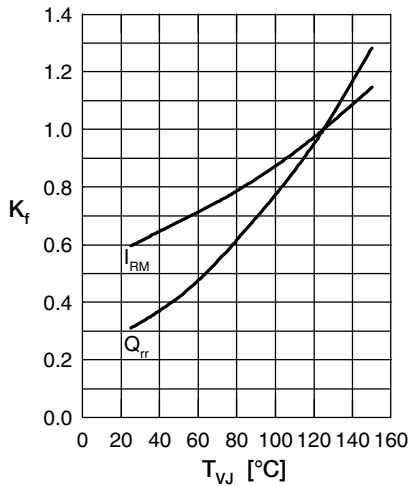


Fig. 4 Typ. dynamic parameters Q_{rr} , I_{RM} versus T_{VJ}

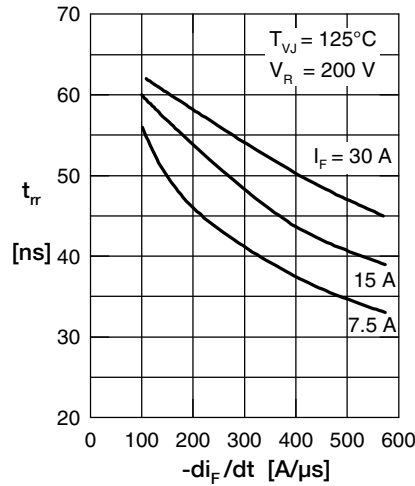


Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

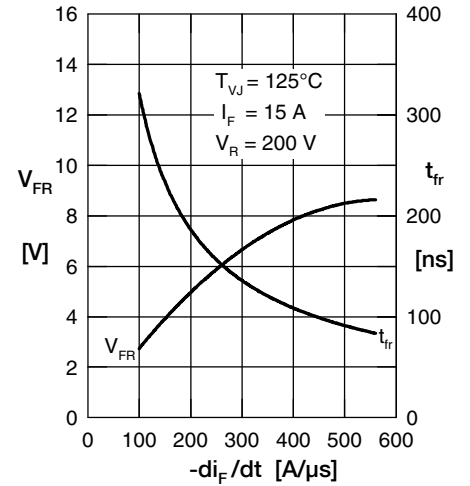


Fig. 6 Typ. peak forward voltage V_{FR} and t_{rr} versus di_F/dt

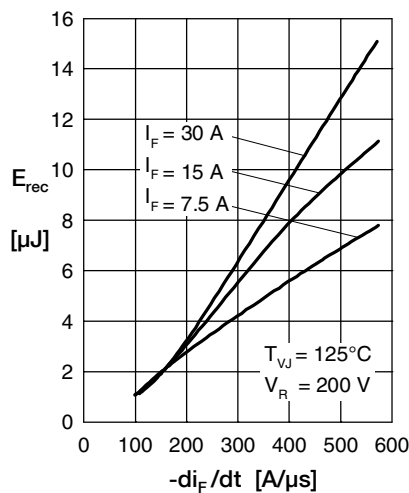


Fig. 7 Typ. recovery energy E_{rec} versus $-di_F/dt$

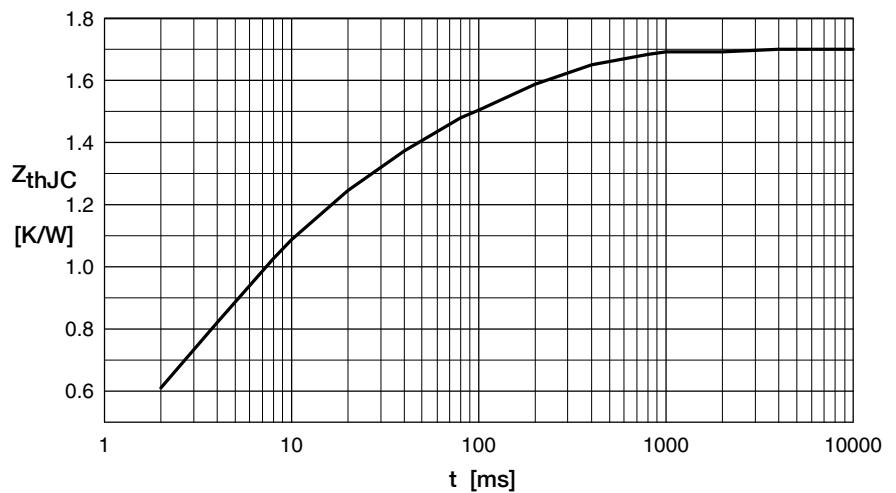


Fig. 8 Transient thermal resistance junction to case